

DFT study of Pt-induced nanowires on Ge(001) I: β -terrace substrate.

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Pt deposited on a Ge(001) surface spontaneously forms nanowire arrays. These nanowires are thermodynamically stable and can be hundreds of atoms long. The nanowires only occur on a reconstructed Pt-Ge-surface where they fill the troughs between the dimer rows on that surface. Because of the unique connection between them, a thorough understanding of the underlying reconstructed surfaces is necessary for understanding the growth of the nanowires. We have studied possible reconstructions containing 0.25 and 0.5 of a monolayer (ML) of Pt. Comparison of calculated scanning tunneling microscopy (STM) images to experimental STM images of the surface reconstruction revealed that the Pt atoms are located in the top layer, creating an antiphased structure with the Pt atoms surrounded by higher positioned Ge atoms. Our results also show that Pt atoms in the second or third layer can not be responsible for the experimentally observed STM images of the β -terrace.

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I. INTRODUCTION

Metal/semiconductor interface interactions continue to attract interest in both fundamental and applied research, and are of vital importance for the semiconductor and microelectronics industry. With miniaturization pushing into the nanoscale regime, new developments are searched for in atomic size reconstructions, self assembly and metal nanowires (NWs).¹ Traditionally, the focus lies on metal/Si interfaces such as e.g. Au/Si(001). For this system, it has been shown that different types of reconstructions appear depending on the Au coverage and the annealing temperature.^{2,3,4} The metal/Ge interface is less well studied, despite its importance in the development of radiation detector systems and high speed electronic devices. Recent experimental studies of the Pt/Ge(001) interface, done at the submonolayer Pt coverage regime, have shown the formation of self-organized Pt NW arrays after high temperature annealing.^{5,6,7} It has been suggested that this reconstruction was due to a strengthened interaction of the 5d metals with the Ge surface: relativistic mass effects which contract the s shell, reducing its energy and thus increase the s occupancy at the expense of the d electrons. This partially depletes the antibonding d states, strengthening the d bonds.⁸ The same mechanism was thought to be responsible for the one dimensional chain structures of Au on Ge.^{9,10} There certainly are similarities between the growth of Au and Pt chains on Ge(001), such as the appearance of Dimer Vacancy complexes before the chains appear. Yet, there are also important differences between the two systems. The Pt NWs only form after annealing at over 1000 K, while the Au chains appear after deposition at 675 K and disappear into the bulk Ge when annealed at 1000 K.^{5,10} Moreover, while the Pt NWs have a thickness of a single Pt atom, the Au chains are dimer rows containing Au-Au or Au-Ge dimers.⁹ The Pt NWs are thermodynamically

stable and their length is only limited by the size of the underlying terrace. This terrace is a previously unknown Pt-Ge-surface reconstruction of which, to date, only a tentative model, as proposed by Gürlü et al., exists.⁵ The unique connection between this terrace and the NWs makes a thorough understanding of the reconstruction desirable before one can study and understand the NW arrays and the physical phenomena associated with them.⁶

In this paper, we present a geometry for the so called β -terraces based on the comparison of the simulated STM images (henceforth referred to as pseudo-STM images) to experimental STM images.¹¹

The structure of the paper is as follows: In Sec. II we describe the applied theoretical method and introduce the index-notation used for the different geometries. In Sec. III we present our theoretical results starting with a comparison of the formation energies of the different geometries followed by a general review of the pseudo-STM images and a discussion of the β_{6u} -geometry as β -terrace in particular. As a last point of Sec. III, we take a look at some geometries containing Pt atoms in the second and third layer and show that these can't be responsible for the β -terrace STM pictures, but they could be responsible for the indented dimer and two dimer vacancy images seen in the STM pictures of the α -terrace.⁵ Finally, in Sec. IV the conclusions are given.

II. THEORETICAL METHOD

A. Setup

Density functional theory (DFT) calculations are carried out using the projected augmented wave (PAW) method^{12,13} and the CA local density approxima-

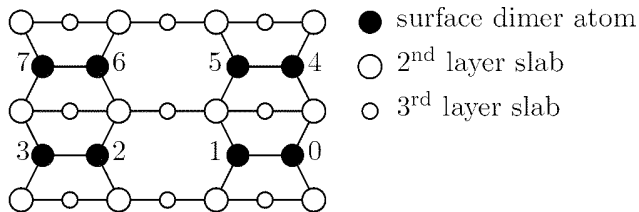


FIG. 1: Top view of the Ge(001) surface with symmetric (2×1) reconstruction. 0 – 7 are indexes for the surface dimer atoms and are used in the nomenclature of the geometries (see text).

tion (LDA) functional, as implemented in the VASP program.^{14,15} A plane wave basis set with kinetic energy cutoff of 287 eV is applied and the semicore d shell of Ge is included in the valence shell for better accuracy. The surface is modeled by periodically repeated slabs of 12 layers of Ge atoms. Extensive convergence tests showed no advantage in time/accuracy for the H-passivated Ge slab over the symmetric Ge slab. Based on symmetry advantages the latter is used. The slabs are mirrored in the z -direction with reconstructions on both surfaces, in which specific Ge atoms are replaced by Pt atoms. A vacuum region of ~ 15.5 Å is used to separate the slabs along the z axis. The Brillouin zone of the $(2 \times 4)\text{R}45^\circ$ surface unit cell is sampled using a $6 \times 3 \times 1$ Monkhorst-Pack special k -point mesh.¹⁶ To optimize the geometry of the slabs the conjugate gradient method is used in zero-temperature calculations. The positions of the Ge atoms in the two center layers are fixed as to represent the bulk phase of the system.

B. Ge(001)-surface and nomenclature

To model the β -terrace we first modeled the clean Ge(001)-surface. Both the buckled $b(2 \times 1)$ and $c(4 \times 2)$ reconstructions using a $(2 \times 4)\text{R}45^\circ$ supercell and the symmetric (2×1) reconstruction were generated using a $(1 \times 2)\text{R}45^\circ$ supercell. After relaxation, the $b(2 \times 1)$ and the $c(4 \times 2)$ reconstruction were found to be 0.302 and 0.374 eV per dimer lower in energy than the symmetric (2×1) dimer. Furthermore, a buckling angle of $\sim 19.5^\circ$ was found for both asymmetric reconstructions, and a dimer length of 2.45 Å for the $b(2 \times 1)$ reconstruction and 2.51 Å for the $c(4 \times 2)$ reconstruction was calculated, all in accordance with previous theoretical and experimental results.^{17,18,19,20}

Based on experimental data,^{5,6} we assume that the β -terrace contains 0.25 ML of Pt. Furthermore, we assume that these Pt-atoms are located in the top layer of the Ge slab (we will show in section IIID that Pt in the second or third layer cannot be responsible for the experimentally obtained STM images). To model the β -terrace, all possible non-isomorphic geometries,

generated by the substitution of two surface Ge atoms, of the $b(2 \times 1)$ surface reconstruction in the $(2 \times 4)\text{R}45^\circ$ supercell, by Pt atoms, were examined. Ignoring the buckling of the Ge dimers for a moment, this leads to seven non-isomorphic geometries. The first Pt atom replaces the Ge surface atom in position 0, while the second Pt atom replaces one of the other seven surface Ge atoms (Fig. 1). We will refer to these geometries as β_1 to β_7 . When the buckling of the Ge dimers in the $b(2 \times 1)$ reconstruction is taken into account, some of the symmetry is lost. Let us assume for a moment that the dimer atoms in Fig. 1 with even index are the down dimer atoms and those with the odd index are the up dimer atoms. We now notice that in some geometries both Pt atoms are located at an up (down)-dimer atom position and in others one is in an up and the other in a down dimer atom position. While for the latter all combinations that are isomorphic stay isomorphic (i.e. when tilting is taken into account) this is not the case in the former situation. Take for example the β_2 geometry with its Pt atoms in positions 0 and 2, an isomorphic geometry in the symmetric reconstruction is one with Pt atoms in positions 1 and 3. In the $b(2 \times 1)$ geometry, as described above, the first β_2 geometry has both Pt atoms at down dimer atom sites, while the second has them at up dimer atom sites. To distinguish these two different geometries, indices u and d are used to indicate the up or down location of the Pt atoms. So the first β_2 geometry is called β_{2d} and the second one β_{2u} .²¹ For geometries with one atom at an up and one at a down dimer atom site both the u and d -index are used to indicate just this (e.g. $\beta_3 \rightarrow \beta_{3ud}$). This results into ten non-isomorphic geometries to start from.

To complete the picture of this system we also included possible geometries containing 0.5 ML of Pt in the top layer. Such a surface then consists entirely of Pt-Ge dimers.²² The three possible geometries considered are a 1×2 reconstruction (γ_1) with all Pt atoms at the even (or odd) positions, a 2×2 reconstruction (γ_2) with all Pt atoms at positions 0, 2, 5 and 7, and a 2×4 reconstruction (γ_3) with all Pt atoms at positions 0, 3, 5 and 6.²³ All these geometries were optimized using the conjugate gradient method while keeping the positions of the Ge atoms in the two center layers fixed.

III. THEORETICAL RESULTS

A. Geometry and formation energy

1. Stability of the β -geometries

The stability of the different geometries was investigated by comparison of their formation energies to the formation energy of the Ge $b(2 \times 1)$ surface reconstruction. The formation energy of a certain geometry, β_x ,

Formation energies and buckling angles.

	E_f (meV)	Pt-Ge buckling (degrees)	Ge-Ge buckling (degrees)
$b(2 \times 1)$	0	-	19.42
$c(4 \times 2)$	-73	-	19.67
β_{1ud}	589	20.57	19.07 (18.25)
β_{2u}	-16	-4.42	21.03
β_{2d}	94	-0.15	18.23
β_{3ud}	34	-4.43(u) -1.82(d)	21.85(u) 18.13(d)
β_{4u}	-61	1.92	18.85
β_{4d}	-25	0.50	18.85
β_{5ud}	83	-5.04(u) 7.38(d)	19.06(u) 18.43(d)
β_{6u}	-25	-4.25	20.82
β_{6d}	82	-0.88	18.13
β_{7ud}	29	-4.83(u) -1.30(d)	21.43(u) 18.06(d)
$\gamma_1 (1 \times 2)$	-47	1.95	-
$\gamma_2 (2 \times 2)$	80	6.13 & -6.46	-
$\gamma_3 (2 \times 4)$	89	5.75 & -6.11	-

TABLE I: The formation energy of the β and γ -surfaces compared to the Ge(001) surface reconstructions and the buckling angles of the dimers. For the β_{1ud} geometry the Pt-Ge dimer buckling refers to the buckling of the Pt-Pt dimer and the value between brackets for the Ge-Ge buckling refers to the buckling of the Ge-Ge dimers located in the same dimer row as the Pt-Pt dimers. The notations (u) and (d) in the column of the Pt-Ge buckling refer to the position of the Pt atom in the dimer, while in the Ge-Ge buckling column they indicate if the Ge dimer is in a dimer row with the Pt atom in the up or down position (except for β_{5ud} where it refers to the location of the Pt atom in a Pt-Ge dimer in the adjacent dimer row). For γ_2 and γ_3 the buckling angles of both dimers of a single dimer row are given.

can be calculated using the expression,²⁴

$$E_f = [(E_{\beta_x} + N_{Pt}E_{Ge}) - (E_{b(2 \times 1)} + N_{Pt}E_{Pt})] / N_{Pt-dimers} \quad (1)$$

with E_{β_x} the total energy of the β_x -geometry, N_{Pt} the number of Pt atoms in the system, E_{Ge} and E_{Pt} the bulk energy of a Ge and a Pt atom, $E_{b(2 \times 1)}$ the total energy of the Ge $b(2 \times 1)$ surface reconstruction and $N_{Pt-dimers}$ the number of surface dimers containing Pt atoms. Negative values for E_f indicate an increase in stability caused by replacing a Ge atom by a Pt atom.

Table I clearly shows the formation energy of the β_{1ud} -surface is much higher than that of the other structures. This is the only structure containing a Pt-Pt dimer; all the others contain mixed Pt-Ge dimers. It shows that replacing a Ge atom in a Pt-Ge dimer with a Pt atom will require about 0.5 to 0.6 eV. This allows to rule out the formation of Pt-Pt dimers in the β terrace. Table I also shows a preference for geometries which contain Pt-Ge dimer rows with the Pt atom in the u position. The entire set of formation energies, with exception of β_{1ud} , is spread over a relatively small energy interval of ~ 150 meV, which is of the same order

of magnitude as the thermal energy corresponding to the annealing temperature.^{5,25} This makes it impossible to exclude additional structures based on energetics.

All formation energies are given per Pt containing dimer. This means that it is the average energy to form a Pt-Ge dimer in the $\beta_2 - \beta_7$ structures.²⁴ In the structures indicated with the ud -subscript the Pt-Ge dimers are not equivalent. The β_{3ud} -structure contains a Pt-up and a Pt-down dimer, while the β_{2u} - and β_{2d} -structures contain either only Pt-up or Pt-down dimers. If we take the average of the formation energy of a Pt-up and a Pt-down dimer from the β_{2u} - and β_{2d} -structures we get 39 meV, the formation energy of an average Pt-Ge dimer in the β_{3ud} -structure. Comparison of the β_{7ud} -structure with the β_{6u} - and β_{6d} -structures gives a similar result. The pattern of Pt-Ge and Ge-Ge dimers in these two sets of three geometries is the same, indicating that the energy due to interactions between neighboring dimer rows is small compared to the formation energy. It also shows the formation energy of the Pt-Ge dimer to depend strongly on the surrounding dimers in the dimer row.

The third triplet of similarly patterned structures (β_{5ud} , β_{4u} and β_{4d}) shows this even more clearly. In this case the average of the formation energy of a Pt-Ge dimer of the β_{4u} - and β_{4d} -structure is -43 meV, much less than the average formation energy for a Pt-Ge dimer in the β_{5ud} -structure. Unlike the previous examples, the Pt-Ge dimers of the β_{5ud} -structure have a different surrounding along the dimer row than those in the β_4 -structures: antiparallel instead of parallel Pt-Ge dimers. This shows that the interaction between neighboring dimers in a single dimer row is strong, and provides a large contribution of the formation energy of a Pt-Ge dimer. It also shows that rotation of a Pt-Ge dimer in the β_{5ud} -surface cell would give an energy gain of roughly $0.2 - 0.3$ eV per surface unit cell.

To make an estimate of the interaction energy between neighboring dimer rows, we compare the β_2 - to the β_6 -structures, the β_{3ud} - to the β_{7ud} -structure, the β_4 - to the γ_1 -structure, and β_{5ud} - to the γ_2 - and γ_3 -structures. It shows that this interaction energy is of the order of about $5 - 10$ meV per Pt-Ge dimer. A similar estimate can be made for the interaction energy along a dimer row by comparing the β_4 - to the β_6 - and the β_{5ud} -structures, and comparing the γ_1 - to the γ_2 - and γ_3 -structures. This gives an interaction energy in the range of $50 - 150$ meV per Pt-Ge dimer, about one order of magnitude larger than the inter-dimer-row interaction energy. It also shows that the proximity of the second Pt atom has a large influence, both for better (β_{4u}) and for worse (β_{5ud}), on the formation energy.

Furthermore, we found that the length of the dimers was not influenced by the geometry, with the sole exception of β_{1ud} . The lengths of the Ge-Ge dimers were found to be 2.45 ± 0.01 Å (2.34 ± 0.03 Å for β_{1ud}) and for the Pt-Ge dimers 2.35 Å (2.58 Å for the Pt-Pt dimer in β_{1ud}). The buckling angles on the other hand

do show a dependence on the location of nearby Pt atoms. Noteworthy is the fact that the Pt-Ge dimers show little to no buckling and the little buckling effect they show depends on the location of the Pt atom: if the Pt atom is located in the up position then the buckling angle is about $4^\circ \sim 5^\circ$, while it is less than 2° when the Pt atom is located in the down position. The sign used for the buckling angles indicates whether dimers are buckled in the same (same sign) or opposite (opposite sign) direction. In all cases, except β_{1ud} and β_4 , the Pt-Ge dimers are buckled in the opposite direction of the Ge-Ge dimers thus creating a (2×2) or (4×2) surface reconstruction. These reconstructions also modify the Ge positions in the second and third layer in a similar way as found for the Ge $c(4 \times 2)$ surface reconstruction.^{17,20} Table I also shows that the Ge-Ge dimers are slightly influenced by the Pt-Ge dimers in the same dimer row, increasing the buckling angle to about $21 \sim 22^\circ$ if it are Pt-Ge dimers with the Pt atom in the up position and decreasing it to about 18° if the Pt atom in the Pt-Ge dimer is in the down position. Another difference between Pt-Ge dimers with the Pt atom in the up or down position becomes clear when they are considered in a dimer row containing both Pt-Ge and Ge-Ge dimers. The Pt-Ge dimer shifts (average of t_3 and t_4 in Figure 8 and Table II) orthogonal to the dimer row. If the Pt atom is located in the up position this shift is very small (~ 0.03 Å) and almost entirely due to the Pt atom moving in the direction of the up position. If the Pt atom is located in the down position, the shift is in the down direction and both the Ge and the Pt atom of the Pt-Ge dimer are shifted over a distance of ~ 0.4 Å.

Comparison of the average z -position of the dimers shows the Pt-Ge dimers to be 0.01 to 0.14 Å lower than the Ge-Ge dimers for each of the considered structures. All the geometrical information of the Pt-Ge dimers combined with the formation energies given in Table I shows a preference for Pt atoms to be surrounded with higher positioned Ge atoms. This can be traced back to the preference for Ge-terminated surfaces in Pt/Ge alloys.²⁶

2. Stability of the γ -geometries

The stability of the γ -geometries was investigated the same way as for the β -geometries. Equation 1 was used to calculate the formation energy per Pt containing surface dimer, making close comparison with the β -geometries possible. The γ_1 -geometry should be compared to the β_{4x} -geometries and the γ_2 and γ_3 -geometries should be compared to the β_{5ud} -geometry. The main difference between these geometries is the presence of a Ge-Ge dimer row in the β -geometries. Table I shows the formation energies for the γ -geometries to be in the range expected

from the comparable β -geometries. As was shown in the previous paragraph, the interaction between neighboring dimer rows is relatively small for β_{5ud} -, γ_2 - and γ_3 -geometries, and a larger part of the formation energy can be attributed to strain between sequential Pt-Ge dimers. For the β_{4x} - and γ_1 -geometries the influence of the neighboring dimer rows is more important. Although the geometry of the Pt-Ge dimer in the γ_1 - and β_{4u} -geometry is nearly indistinguishable, and thus quite different from that of the one in the β_{4d} -geometry, the formation energy is about the average of that of the β_{4u} - and the β_{4d} -geometry. The geometries of the Pt-Ge dimers in the β_{5ud} -, γ_2 - and γ_3 -geometries are almost identical and the angle between the antiphase Pt-Ge dimers in a dimer row is in each case about 12° with the Pt atoms on the geometrically lower side of the dimer. Furthermore, looking at the positions of sequential dimers in a dimer row, a shift orthogonal to the dimer row is observed. This shift increases the distance between the Pt atoms with $0.56 - 0.61$ Å in the direction orthogonal to the dimer row. It is larger than any of such shifts produced with normal Ge-Ge dimers in the dimer row, indicating the crucial role of the Pt atoms in this matter.

B. Electronic structure

1. General properties of the β -geometries

Since there is no clear evidence, based on energetics alone to put forward a single reconstruction as *the* β -terrace, a more direct comparison with the STM observations is needed. This was done by calculating the local density of states (LDOS) $\rho(\mathbf{r}, \varepsilon)$.²⁷ The theoretical LDOS was calculated as $\bar{\rho}(\mathbf{r}, \varepsilon) \propto \int_{\varepsilon}^{\varepsilon_F} \rho(\mathbf{r}, \varepsilon') d\varepsilon'$, with ε_F the Fermi energy. A surface of constant density is then constructed according to $\bar{\rho}(x, y, z, \varepsilon) = C$, with C a real constant. This construction gives the height z , as a function of the lateral position x, y , which is mapped linearly onto a gray scale. This mimics the presentation of STM images in the usual constant-current mode of operation.

Figure 2 shows some pseudo-STM images of the β_{2u} -, β_{2d} - and β_{7ud} -surface for both filled and empty states. The filled state image of the β_{2u} -surface shows a bright peak above the up-atom of the Ge dimer and a slightly less bright peak above the Ge atom of the Pt-Ge dimer. This creates a zigzag pattern of bright spots (of two different intensities). Comparison of the filled-state pictures of the β_{2u} - and β_{2d} -surface, shows images for the Pt-Ge dimers that are clearly different. Where there is a clear peak when the Pt atom was located between up-Ge atoms (β_{2u}) there is a relatively evenly spread rectangular feature when the Pt atom is located between down-Ge atoms (β_{2d}). This feature is spread out over the atoms of the Pt-Ge dimer and is slightly higher at the position of the Ge atom. The difference in height is

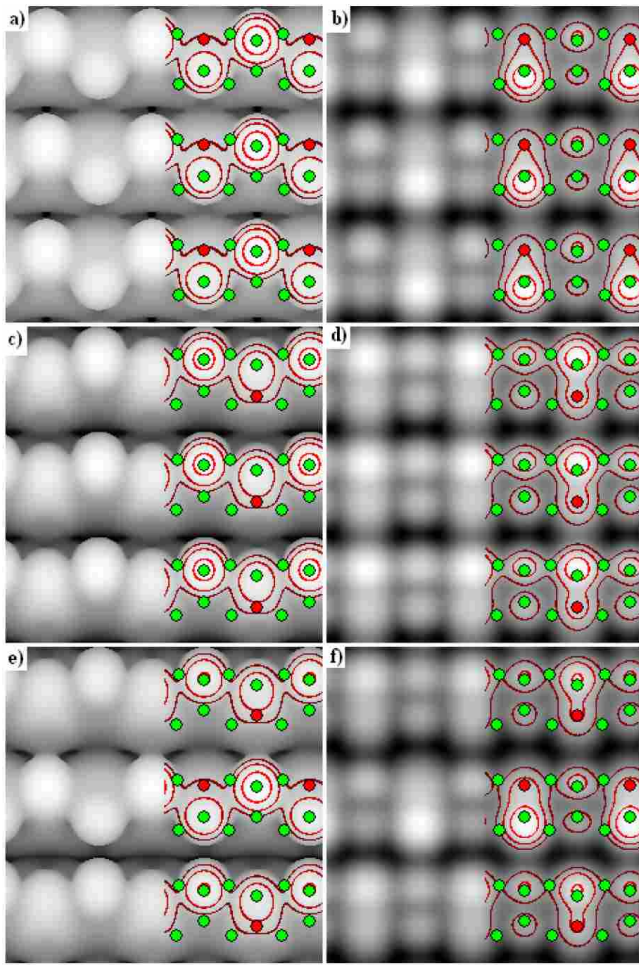


FIG. 2: (Color online) Pseudo-STM images showing filled (a,c,e) and empty (b,d,f) states of the β_{2u} - (a,b), β_{2d} - (c,d) and β_{7ud} - (e,f) geometries. For the filled-state images $\varepsilon = \varepsilon_F - 0.70\text{eV}$ and for the empty-state images $\varepsilon = \varepsilon_F + 1.50\text{eV}$ was used. The constant density used is chosen such that the maximum z is at $3.0\text{\AA}$ above the highest atom. The small black (red) filled circles represent the Pt atoms in the top layer, the small grey (green) circles represent the positions of the Ge atoms in the two top layers. Contours were added to show the main features discussed in the text.

five times smaller than the difference in height between the locations of the two Ge atoms in the Ge dimer. The Pt-Ge feature, in the β_{2d} filled-state picture, has a height equal to the average height of the Ge dimer and does not protrude as far in the trough between the dimer rows as the Ge dimer. This gives the overall impression of 'battlements'.

The β_{7ud} -surface contains both a Pt atom between up-Ge atoms and one between down-Ge atoms. As could be expected from the filled-state images of the β_{2u} - and β_{2d} -surfaces the filled-state image of the β_{7ud} -surface shows a zigzag row and a battlement row alternatingly. A further study of the pseudo-STM images of the other β -geometries shows these same structures reappearing in different combinations.

A Pt atom located between up-Ge atoms causes a feature which is about three times as steep as the feature caused by a Pt atom between down-Ge atoms. The Pt atom is also always located at the lower end of these features, even though sometimes the geometry shows the Pt atom to be the higher atom of the dimer. For the β_{4x} -geometries, the dimer row of the Pt-Ge dimers shows a $b(2 \times 1)$ structure while a $c(2 \times 2)$ structure is found for the β_{5ud} -geometry. This Pt-Ge dimer row is always a much dimmer than the Ge dimer row, but it still shows nicely distinct dimer patterns. Another careful look at the pseudo-STM structure of a Pt-Ge dimer with the Pt atom between up-Ge atoms shows that unlike the Ge-dimer this structure has a dim tail directed toward the Pt atom. Although this is best visible in the empty-state pictures of Figure 2, it is present for both filled- and empty-state images.

The above analysis of the pseudo-STM images shows that the filled-state images of single dimers can be used as building blocks to reconstruct the geometry of the β -terrace (this will be shown in section III B 4).

The empty-state pseudo-STM images for a bias far above the Fermi level show a very simple picture, with little or no dependence of the position of the Pt atoms on the neighboring Ge atoms. The Ge dimer shows up as a set of two separate confined peaks, while the Pt-Ge dimer is smeared out, showing a bright ball on the side of the Ge atom and a dim wide tail on the side of the Pt atom. Though the Pt-Ge dimer images look very similar in the empty-state pseudo-STM pictures, they are not exactly the same. The empty-state picture of β_{7ud} in Figure 2 shows clearly that the Pt-Ge dimer with Pt in the up position is slightly brighter and has a somewhat more egg-like shape. Close to the Fermi level, the pseudo-STM images of filled and empty states are nearly indistinguishable and some interesting features appear in the pseudo-STM images. The most eye-catching feature is the notch in the isosurface, along the dimer row. It is caused by the Pt atom as seen in Figure 3. Though clearest for the Pt atom between up-Ge atoms in a filled-state images and clearest for the Pt atom between down-Ge atoms in the empty-state images, both are present at either side of the Fermi level and were found in all geometries. Checking contour plots of cutthroughs in the z direction at the position of these notches, showed they are caused by the gap between two lobes of the d -orbitals of the Pt atom underneath.

2. General properties of the γ -geometries

The pseudo-STM pictures of the γ -geometries show in general the same image for the Pt-Ge dimer rows as was seen for the corresponding Pt-Ge dimer rows in the β_{4x} and β_{5ud} pictures. For the γ_1 -geometry, the pseudo-STM pictures show dimer rows with a bright spot at the Ge dimer atom position. This spot becomes sharper when

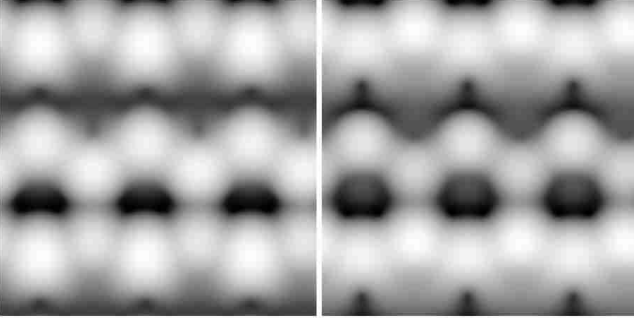


FIG. 3: Pseudo-STM images showing filled (left) and empty (right) states of the β_{7ud} -geometry close to the Fermi level. $\varepsilon = \varepsilon_F \pm 0.30$ eV was used. The maximum z is at 4 Å above the highest atom. There is a clear difference between the dimer rows with the Pt atoms located between up-Ge atoms (middle zigzag row) and the dimer rows with the Pt atoms located between down-Ge atoms (top and bottom row). A notch in the constant density surface above the location of the Pt atoms is visible for both the filled- and empty-state image.

the bias becomes smaller, both above and below the Fermi energy. The γ_2 - and γ_3 -geometries show nearly identical pictures, the main difference being the phase-shift between neighboring dimer rows, which causes the appearance of a very dim (at least 1.5 Å lower than the dimer peaks in the pseudo-STM pictures) bridge between the Pt atoms of neighboring dimer rows. This bridge is most clear in the empty state pictures. Again it is the Ge side of the Pt-Ge dimers which lights up very bright, causing a zigzag pattern of bright spots along each dimer row. For small biases this zigzag pattern becomes more pronounced and also the notch above the Pt atoms appears. At a large negative bias the bright spot has a dim tail directed toward the Pt atom. All Pt-Ge dimer images for γ_2 and γ_3 are identical, unlike for the β -geometries.

3. β_{6u} -structure as geometry for the β -terrace

In this paragraph we will show that, although most β -structures studied are energetically available, only the β_{6u} -geometry can be related to the experimentally observed β -terrace. Figures 4 and 5 show (experimental) STM images of the β -terrace at biases of -0.30 V and $+0.30$ V. The filled-state image clearly shows two types of dimers alternating in each dimer row. One of the dimer types shows up as a big bright spot on one side of the dimer row while the other dimer type shows up as a smaller somewhat dimmer spot on the other side of the dimer row, with a dim tail extending to the opposite side of the dimer row. These are the only two types of dimers appearing in the image. Comparing this to the results of the pseudo-STM images seen in the previous paragraph, the first type of dimer is the Ge-Ge dimer while the second type of dimer presents all the typical features of the

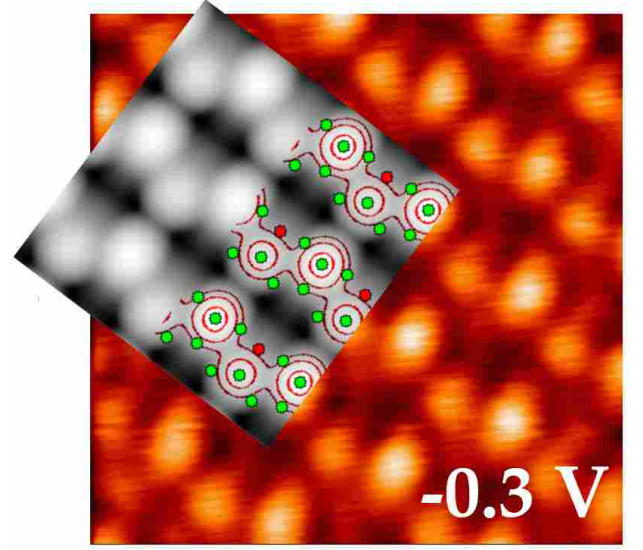


FIG. 4: (color online) Comparison of the filled-state pseudo STM image of the β_{6u} -geometry (gray scale overlay) with the corresponding experimental STM image of the β -terrace. The STM image was obtained using a sample bias of -0.3 V, while the pseudo STM image was generated using $\varepsilon = \varepsilon_F - 0.70$ eV and a maximum z of 4 Å above the highest atom. The small black (red) filled circles represent the positions of the Pt atoms in the top layer, while the gray (green) discs represent the positions of the Ge atoms in the top two layers. The quasi dimer rows (QDRs) are clearly visible, in both STM images, as is the presence of two different dimer types.

Pt-Ge dimer with the Pt atom located between up-Ge atoms. This allows us to exclude all β -geometries containing Pt at a down location, leaving only the β_{2u} -, β_{4u} - and β_{6u} -geometry. Taking the phase shift of neighboring dimer rows into account the geometry which represents the β -terrace can only be the β_{6u} -geometry. Filled- and empty-state pseudo-STM images of the β_{6u} -geometry are displayed on top of the experimental pictures in Figures 4 and 5. The empty-state pseudo-STM image (Fig. 5) shows some very specific features of this geometry. There are *triangular holes* where the Pt atom is located and the Ge atoms of the top layer also create a triangular feature dominated by the zigzag structure of the up-Ge atoms and the Ge atoms in the Pt-Ge dimers. Comparison of the empty-state images in Figure 5 reveals the existence of these features in both images, further strengthening our belief that the β_{6u} -geometry is the geometry of the β -terrace. Another look at Table I also confirms this geometry to be more stable than the Ge $b(2 \times 1)$ surface reconstruction. Furthermore, for the β_{6x} -geometries, the Pt atoms are also distributed in the most homogeneous way, decreasing the long range interaction between neighboring Pt atoms. The pseudo-STM images show only for the β_{6u} -geometry this level of agreement with the experimental STM images, allowing the β_{6u} -structure to be presented as *the* geometry of the experimentally observed β -terrace.

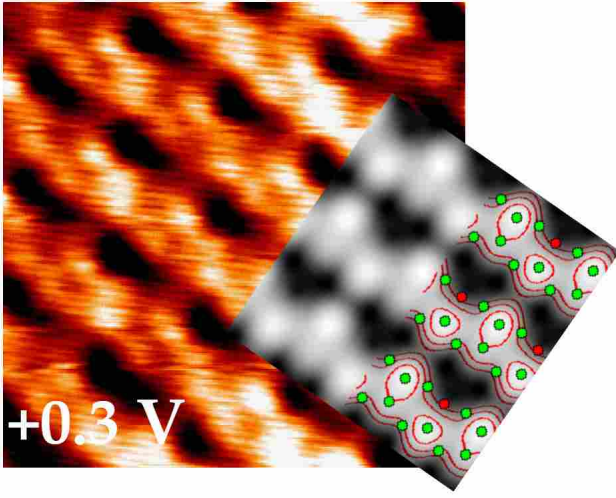


FIG. 5: (color online) Same as Figure 4 but now for the empty-state images. The sample bias used for the STM image was 0.3 V and $\epsilon = \epsilon_F + 0.70$ eV was used for the pseudo STM image.

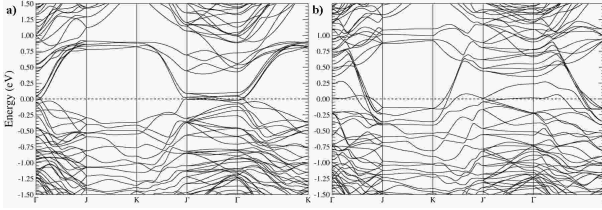


FIG. 6: Comparison of the band structure, along high symmetry lines, of the Ge(001) $c(4 \times 2)$ reconstruction (a) and the β_{6u} -geometry (b). The zero energy is at the Fermi level.

Figure 6b shows the band structure of the β_{6u} -geometry along the high symmetry lines Γ -J-K-J'- Γ -K of the surface Brillouin zone. Figure 6a shows the band structure of the Ge(001) $c(4 \times 2)$ reconstruction along the same lines for comparison. In general, the two band structures show similar behavior. Perpendicular to the dimer row direction, along the J-K and J'- Γ line, the bands show little dispersion. Along the J'- Γ line, a few of these bands cross the Fermi level. The main difference between the two band structures is located along the Γ -J and K-J' lines. For the β_{6u} -structure we find bands with a strong dispersion opposite to what is seen for the Ge(001) surface. Furthermore, these bands also cross the Fermi level in the second half of the Γ -J line, resulting in the metallic behavior observed for the β -terrace.²⁸ Taking a closer look at these specific bands near the crossing of the Fermi level, we find that their character contains three main components. The largest component has a Pt-like character. The other two (smaller) components have a Ge-like character: more specifically, the second layer Ge atoms bound to the Pt atoms in the top layer and the top layer Ge atoms in between the Pt atoms. The orbital character of the Pt contribution is mainly p_x , p_y

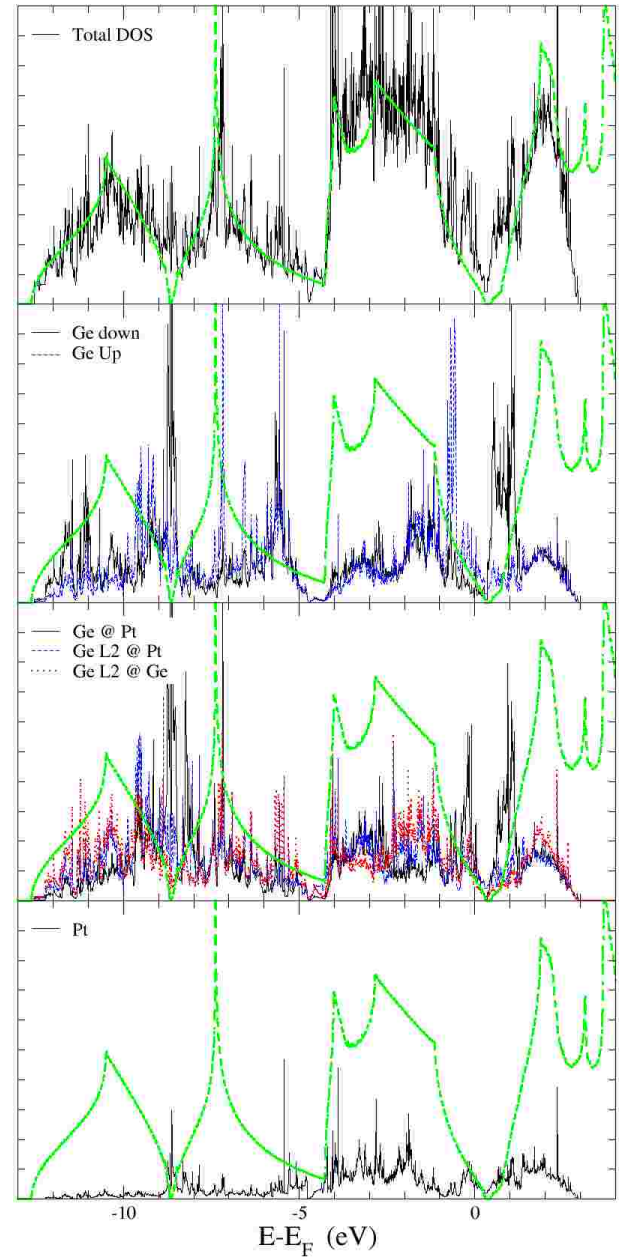


FIG. 7: (color online) Total DOS of the β_{6u} -geometry and the LDOS of the surface atoms. The bold dashed green line shows the DOS of Bulk Ge, it was shifted to align the edges of the BG regions.

and d_{xz} , d_{yz} , making it highly planar. The Ge contribution depends on the Ge atoms involved. The orbital character of the contribution of second layer Ge atoms is mainly sp^3 , while the top layer Ge atoms bound to the Pt atom contribute mainly a p_z orbital character, indicating the presence of a π -bond with energy close to the Fermi level for the Pt-Ge dimer. Interestingly, the Ge atoms in between Pt atoms along the dimer row have a significant contribution to most of the bands we are interested in. The orbital character in this case is mostly p_x and p_y .

The presence of bands close to (and crossing) the Fermi level connected to an orbital character directed along the dimer row direction, indicates the possible presence of surface conduction channels along this direction. These could then be the source of the confined states observed in Ref. 6 and 29.

Figure 7 shows the density of states (DOS) of the β_{6u} -geometry and the local DOS (LDOS) of the surface atoms.³⁰ The total DOS roughly shows the DOS observed for bulk Ge, as could be expected. The main difference is found in the band gap (BG) region. Here, three distinct peaks can be observed. The two outer peaks are also observed for a reconstructed Ge(001) surface, where they are linked to the dangling bonds of the Ge surface dimer atoms. Since half the surface dimers of the β_{6u} -geometry are Ge dimers, it is not surprising to observe these states. The second image from the top in Figure 7 shows the LDOS of the up and down atoms of the Ge surface dimers. Comparison to the Ge(001) $c(4 \times 2)$ and $b(2 \times 1)$ reconstruction, shows the peak due to the Ge-down atom to be quite broad, comparable to what is found for the $b(2 \times 1)$ reconstruction. This broadening probably originates from the small tilt-angle of the Pt-Ge dimers, moving toward an atomic height structure similar to that of the $b(2 \times 1)$ reconstruction.

The LDOS image of the Ge atoms bound directly to the Pt atom shows something interesting. The Ge atom of the Pt-Ge dimer also has two peaks in the BG region. A sharp peak around the same value as seen for the Ge down atom at the conduction band (CB) side, and a second peak near the valence band (VB) side of the BG region. This second peak is located just at the Fermi level.

The second layer Ge atoms (indicated with L2 in Fig. 7) show roughly the same structure, however, in the BG region it are the second layer Ge atoms bound to the Pt atoms of the top layer that have only non-zero values. Together with the Ge up (which also show this behavior) and Pt atoms, they form a corridor of 'metallic' atoms along the edge of the dimer row, in agreement with what was shown from the band structure and what was observed experimentally.²⁸

4. Experimental existence of other β -geometries

Although the comparison between experimental and pseudo-STM images in Figures 4 and 5 shows clearly that the clean β -terrace has a β_{6u} -geometry, the formation energies given in Table I make us suspect that also other geometries should be observed experimentally. Investigation of experimental STM images has shown the existence of (small) regions where dimer rows contain a mix of different (non β_{6u}) geometries. These geometries were mostly found near distortions of the normal β -terrace, such as dimer vacancies and the endpoints of a nanowire. Because these geometries seem related to defects, we will not go into the details of their

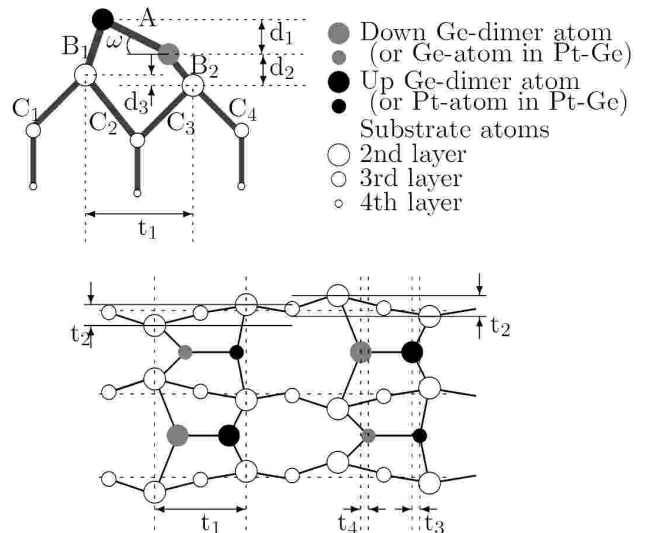


FIG. 8: Top: Diagram showing the side view of a relaxed Ge-Ge dimer, including the labeling used for both Ge-Ge and Ge-Pt surface dimers.

Bottom: Top view schematic representation of the β_{6u} -reconstruction.

geometry and focus solely on the β_{6u} -geometry.

C. The β_{6u} -geometry

The structural results obtained from relaxing the β_{6u} -geometry, starting from the $b(2 \times 1)$ -geometry, show a (4×2) -reconstruction. As can be seen in Table II, the Pt-Ge dimer and the Ge-Ge dimer have an opposite buckling angle. Figure 8 shows a schematic representation of this geometry. The horizontal dashed lines in the bottom picture represent the equilibrium dashed location of second and third layer atoms of the Ge $b(2 \times 1)$ -reconstruction. Comparison of the β_{6u} -geometry (Fig. 8) with the $b(2 \times 1)$ -geometry (Fig. 1) shows a slight shift of the second and third layer atoms. Near the up-Ge/Pt atom the second layer Ge atom is shifted away from the Pt atom. The other second layer atom is shifted toward the Pt-Ge dimer. *Twisting* of the second layer atoms around the third layer atom position, as present in the Ge (2×2) and Ge $c(4 \times 2)$ -reconstructions, is also present in the β_{6u} -geometry, albeit as only one out of three deformations acting on the original $b(2 \times 1)$ geometry.³¹ Unlike the reconstructions of pure Ge the twisting around the third layer atom in the β_{6u} -geometry has a large asymmetry. Where the ratio, of the contributions to t_2 , of C_2 to C_3 is 1 : 1 for Ge reconstructions, it is 6.3 : 9 for the β_{6u} -reconstruction, i.e. the second layer Ge atom is pulled toward the Pt atom compared to the Ge $c(4 \times 2)$ -reconstruction. This twisting of the tetrahedral arrangement in the substrate has been described in the literature

Bond lengths and dimer tilt angle.

	ω	A	B ₁	B ₂	C ₁	C ₂	C ₃	C ₄	d ₁	d ₂	d ₃	t ₁	t ₂	t ₃	t ₄
Ge b(2×1)	19.42	2.450	2.512	2.426	2.475	2.449	2.543	2.475	0.815	0.775	0.099	3.818	0	0	0
Ge c(4×2)	19.60	2.511	2.506	2.430	2.463	2.481	2.481	2.462	0.842	0.749	0.007	3.817	0.283	0.335	0.332
β_{6u} Ge-dimer	20.82	2.462	2.552	2.433	2.479	2.435	2.492	2.469	0.875	0.731	0.027	3.764	0.153	0.049	0.003
β_{6u} Pt-dimer	-4.25	2.354	2.378	2.521	2.479	2.435	2.492	2.469	0.174	1.358	0.027	3.764	0.153	0.049	0.003

TABLE II: Bond lengths and distances in Å and the dimer tilt angle ω in degrees. All as defined in figure 8.

as a mechanism to relieve strain, by replacing some of the asymmetry in the dimer-bond direction by asymmetry in the dimer row direction. From Table II follows that the ratio of the twisting (t_2) of the β_{6u} -geometry to that of the Ge c(4×2)-geometry is about 0.54. This can easily be understood from the origin of this twisting. The strain which is being relieved by the twisting is related to the angle (orthogonal to the surface) between subsequent dimers in a dimer row. The ratio of these angles is then equal to that of the twisting. A quick check shows this is not the case, the ratio found for the angles is about 0.64. This is because two types of atoms are present in the surface dimers. The inhomogeneity of the β_{6u} -system can be taken into account by adding the mass percentage of the dimers as a weight factor to the angle contributions. The angular ratio is now given by:

$$R = \frac{\left(\frac{M_{\text{Ge}} + M_{\text{Pt}}}{3M_{\text{Ge}} + M_{\text{Pt}}} \right) \omega_{\beta_{6u} \text{ Pt dimer}} + \left(\frac{2M_{\text{Ge}}}{3M_{\text{Ge}} + M_{\text{Pt}}} \right) \omega_{\beta_{6u} \text{ Ge dimer}}}{\omega_{c(4 \times 2)}} \quad (2)$$

with M_x the mass of a single atom of type x and ω_y the angle ω shown in Table II for the y surface reconstruction. Using eq. 2 a value of 0.514 is found, in agreement with the value found for the ratio of the t_2 parameters. This shows t_2 to be a useful parameter for comparison of the asymmetry induced strain in these systems. As a result, the difference of the twisting parameter, t_2 , between the Ge c(4×2) and β_{6u} -reconstruction can be attributed entirely to the introduced Pt atoms. First, by levelling out the Pt-Ge dimer and second, through the contribution in the mass for the weight factor.

The presence of two different dimer types in the β_{6u} -geometry complicates the image of twisting of second and third layer Ge atoms even further. Figure 9 gives, somewhat exaggerated, diagrams of the top view of a row of second and third layer Ge atoms in geometries with increasing complexity. The horizontal dashed lines give an arbitrary zero-line with regard to which all amplitudes are given. The Ge (2×2)-reconstruction shows the simple image of *twisting* of the tetrahedral arrangement, caused by the asymmetry of oppositely buckled dimers (not shown) in the same dimer row. The image of the Ge c(4×2)-reconstruction presents a *bending* of the entire structure (indicated by the gray curve) caused by the asymmetry between the C₁, C₄ and the C₂, C₃ bonds as a result of the opposite buckling of dimers in adjacent dimer rows. The introduction of Pt atoms in the β_{6u} -geometry makes the picture even more complicated.

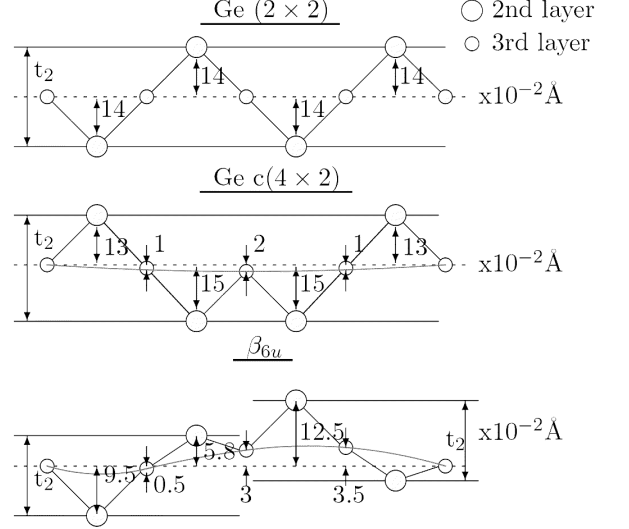


FIG. 9: The diagrams show a top view of the upper row, as represented in the diagram of the β_{6u} -reconstruction in figure 8, of second and third layer Ge atoms in a Ge(2×2)-, Ge c(4×2)- and β_{6u} -reconstruction. The adjacent top layer atoms, as represented in a diagram like the one in fig.8, are then from left to right:

Ge (2×2): Ge up-dimer atom, down-dimer atom, up-dimer atom and down-dimer atom.

Ge c(4×2): Ge down-dimer atom, up-dimer atom, up-dimer atom and down-dimer atom.

β_{6u} : Ge atom, Pt atom, Ge down-dimer atom and Ge up-dimer atom.

(Data for the Ge (2×2)-reconstruction was taken from Gay *et al.*)

On top of the previous two distortions a shift is introduced due to the asymmetry of having different atom types in the system. It shifts the cell, which defines the twisting parameter in a dimer row, along this dimer row, away from the Ge-Ge dimer and toward the Pt-Ge dimer. This twisting is out of phase in the adjacent dimer rows, due to the phase shift between the dimer rows of the β_{6u} -geometry, giving rise to the *shift*. This shift can be seen as a consequence of the induced asymmetry in the t_2 contributing components of the C₂ and C₃ bonds. Furthermore, the Pt atoms in the top layer dimers increase the amplitude of the bending by a factor of two and the extrema of the bending curve shift from the third layer

atoms between the dimer rows to the third layer atoms underneath the dimer rows. Figure 8 shows the shift is toward the Pt-Ge dimer, shrinking the surface cell containing the Pt-Ge dimer in favor of the Ge-Ge dimer surface cell. Table II also shows a decrease in the parameter t_1 , reducing the size of the Pt-Ge dimer surface cell even further and partially compensating the expansion of the Ge-Ge dimer surface cell. Comparison of the values for t_2 with those of Gay *et al.*²⁰ shows that for the β_{6u} -surface the value of the twisting parameter t_2 is comparable with that of Ge/SiGe(up) structure.³² The bond length of the Ge-dimer in the β_{6u} reconstruction is only slightly longer than it was in the $b(2 \times 1)$ -reconstruction but still significantly shorter than it is in the $c(4 \times 2)$ -reconstruction. The accompanying change in buckling angle accounts for this slight elongation. Also, the back bonds of the Ge atoms of all dimers are longer than their counterparts in the asymmetric Ge surface reconstructions. This while the height of these back bonds for the Ge-Ge dimers is similar to the one found for the $c(4 \times 2)$ -reconstruction. t_3 and t_4 show us the shift between sequential dimers in a single dimer row. Although they are not zero, they are at least one order of magnitude smaller than the values obtained for the $c(4 \times 2)$ -reconstruction, and unlike the $c(4 \times 2)$ -reconstruction there is an asymmetry between the two shifts. The C_n -bonds between the second and third layer Ge atoms have lost all symmetry, this is because there are two types of surface dimers in play, unlike the reconstructions studied by Gay *et al.*

D. Other geometries

Though the previous section shows clearly the β -terrace has a β_{6u} -geometry, it is still interesting to have a look at some geometries containing Pt atoms in the second or third layer of the system. Previous calculations and experimental observations have shown that Pt atoms prefer to occupy subsurface positions.³³ Before the transformation to the β -terrace, there is what Gürlü *et al.* call an α -terrace. This type of terrace is characterized by its large number of dimer vacancy defects.

Also, in this initial stage of Pt growth on Ge(001) there are still a number of features which aren't entirely understood, e.g. *indented dimers*.

Figure 10 shows the positions where Ge atoms were substituted with Pt atoms in the second and third layer of the system. The final geometries were obtained the same way as the β -geometries, i.e. substitution of Ge atoms by Pt atoms in a Ge(001) $b(2 \times 1)$ -reconstructed slab and relaxation of the geometry using the conjugate gradient method keeping the positions of the two center layers fixed.

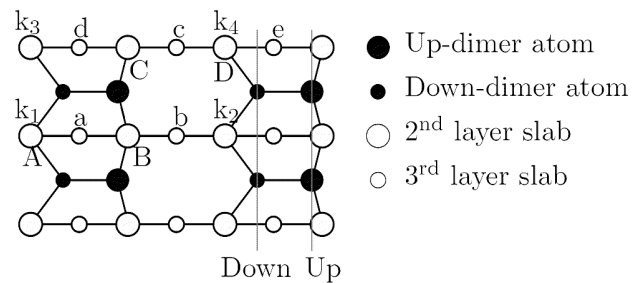


FIG. 10: Locations of Ge atoms substituted by Pt atoms in the second (capital) and third (small) layer. The notations k_1 and k_2 show the second layer Ge atoms pushed to the surface by third layer Pt atoms.

1. Pt in the second layer

When Ge atoms in the second layer are substituted with Pt atoms, there are two possible inequivalent sites to consider. One under the down Ge atoms and one under the up Ge atoms of the surface dimers. Table III shows the formation energy per Pt atom for these two locations differs only 64 meV and Pt favors the position under the up Ge dimer atoms. Table III also shows that the introduction of a second Pt atom in the second layer improves the stability of the system considerably, increasing the formation energy by 28 and 123 meV per Pt atom. This difference from what would be expected from the single Pt substitution results, shows there is a strong positive correlation between the Pt atoms in the second layer. Furthermore, comparison of Table I and Table III shows the formation energies per surface unit are roughly in the same range as the formation energies per surface unit of the studied β - and γ -geometries, making these structures energetically also viable candidates as source of the β -geometry. Pseudo-STM images on the other hand clearly show this is not the case. The top part of Figure 11 shows the influence of the substitution of a single Ge atom by a single Pt atom in the second layer of the system. In both cases the images of the two Ge dimers on top of the Pt atom merge into one image, with the location of the overlap on the side where the Pt atom is located.

For a Pt atom located at the down side this fusing is only seen for small bias voltages, for large bias the images are almost indistinguishable from the normal Ge dimer images. Also, the brightness of the dimers is roughly the same as for the Ge dimers on a normal Ge(001) surface.

In case the Pt atom is located at the up side of the dimer row, the position where the two images of the Ge dimers merge moves from being on top of the Pt atom, for large negative biases, to being on top of the Ge atom in between two Pt atoms, for small negative biases and all positive biases. Also, in this case there is a clear difference in brightness between the normal Ge dimers and the dimers on top of a Pt atom. For negative biases, the

Formation energy.

Layer	position(s)	E_f (meV)
2	A (down)	24
2	B (up)	-40
2	A & D (down)	-4
2	B & C (up)	-163
3	a (row)	-1115
3*(k_1)	a (row)	-155
3	b (trough)	68
3	a & b	-630
3*(k_1 & k_2)	a & b	467
3	a & c	-467
3*(k_1)	a & c	-66
3	a & d	-616
3*(k_1 & k_3)	a & d	-32
3	a & e	-1141
3*(k_1 & k_4)	a & e	-346

TABLE III: Formation energy per Pt atom of reconstructions containing Pt atoms in the second and third layer. The positions are shown in figure 10. The star indicates that the Ge atoms at the k_x positions (between brackets) are removed from the system, and the values were obtained after relaxation of these modified systems.

normal Ge dimers are most bright while for positive biases, the modified dimers are brighter. The brightest part of the modified dimers extends over the entire dimer for small biases, while for large positive (and negative) bias the brightest part of the image is at the side of the up Ge atoms. This gives the impression of a dimer located at one side of the dimer row, and directed along this dimer row. This is only an impression because these structures are formed by the bending, toward and away from the Pt atom, of the Ge p orbitals. When all Ge atoms at the up side in the second layer under a dimer row are substituted by Pt atoms, the images of the above Ge dimers don't merge anymore. Their image only lengthens and becomes a long oval shape which is dimmer than the normal Ge dimer at negative bias and brighter than the normal Ge dimer at positive bias. This elongated shape persists at positive bias such that there is a clear difference between this image and the image of a normal Ge dimer, for which the single dimer image is replaced by two spots, one for each Ge atom.

2. Pt in the third layer

Substitution in the third layer can also be done at two inequivalent sites. The first is under the dimer row and the second is in the trough, between dimer rows. Table III shows a clear preference for Pt to be positioned under a dimer row, while a Pt atom in the trough position is less favorable than the original $b(2 \times 1)$ -reconstruction. This again shows the preference of Pt to be surrounded by Ge atoms.³⁴ Table III also shows that the introduc-

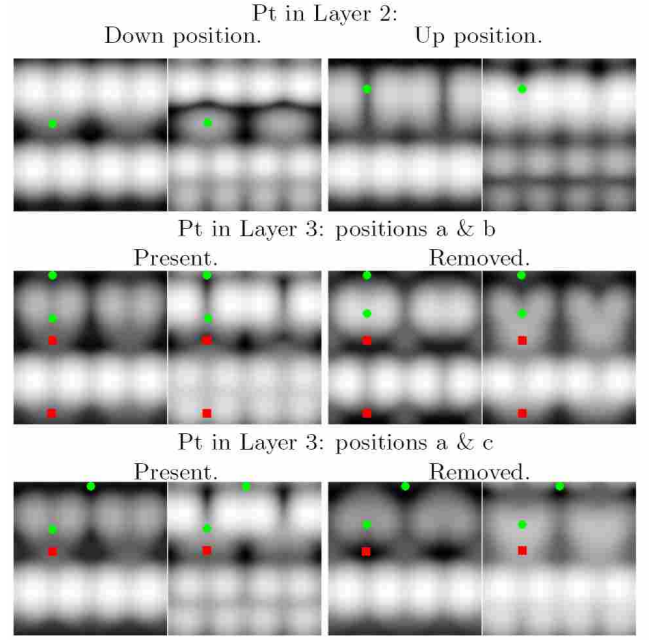


FIG. 11: (Color online) Pseudo-STM images showing filled- (left of each pair) and empty- (right of each pair) state images of the geometries containing Pt in the second and third layer. $\varepsilon = \varepsilon_F \pm 0.70$ eV was used for this simulation and the maximum z was chosen at 4 Å above the highest atom. The position of the Pt atoms are indicated by the (green) circles and the (red) squares indicate the positions of second layer Ge atoms which are pushed up to the first layer level. Present and removed refers to these Ge atoms being present or having been removed (star configurations of Table III). The bottom dimer row in each picture shows Ge dimers which are not (or barely) influenced by the Pt atoms present. The dimers at the top of each picture show a clear modification caused by the Pt atoms present underneath.

tion of a second Pt atom in the third layer about halves the formation energy per Pt atom, if the second Pt is located at a nearest neighbor position. Though this might be expected for a combination of one row and one trough positioned Pt atom, it is also the case for two Pt atoms in row positions. Unlike Pt in the second layer, Pt in the third layer prefers to be positioned far from other Pt atoms. Positions a and e seem to be separated enough to remove this negative correlation. Comparing Table I and Table III shows clearly that Pt under a dimer row is energetically the most favorable configuration, with a formation energy about one order of magnitude larger than the other configurations, in agreement with previous calculations.⁵

Geometrically the most impressive change is caused by a Pt atom under a dimer row. The atom pushes the second layer Ge atom (indicated with k_x in Figure 10) at the down side of the row up to the first layer deforming the surface geometry. Even in case of the geometry containing Pt atoms at positions a and b . There the lifting of Ge atom k_2 might be considered caused by the

Pt atom at position a . This Pt atom pushes Ge atom k_1 up to a first layer position, but it also pushes the Ge atom in between the two Pt atoms a little bit away. This Ge atom in turn pushes against the second Pt atom which then lifts Ge atom k_2 creating a chain effect in which a horizontal shift is transformed into a vertical one. Table III shows the removal of these Ge atoms (after relaxation to a new equilibrium geometry) costs about 0.6 to 1.1 eV per Ge atom removed. So if the Ge atoms are to be considered as ejected atoms which move away to a position at a step edge, then the energy gained from placing a Pt atom in a row position is almost entirely lost and we again end up in the energy range of the β - and γ -geometries. The exception being the geometry placing Pt atoms in positions a and e , which resembles the β_6 -geometry, and thus could be considered a possible starting position for the β_{6u} -geometry.

The influence on the pseudo-STM pictures is similar as seen for the Pt atoms in the second layer. The charge lobes of the up Ge dimer atoms are pulled toward one another over the Pt atom at negative bias while for positive bias they are pushed away. For the down Ge dimer atoms, the charge lobes are always pulled toward one another over the Pt atom. The merging of the dimer images in the pseudo-STM pictures of Figure 11 show this nicely. A more important effect caused by this deformation of the charges is the dimming at negative and the brightening at positive biases of the nearby Ge dimers, which can be substantial, as shown in Figure 11. This indicates a charge transfer from Ge to Pt atoms. Removal of the k_x Ge atoms forces the down Ge atoms to make a new bond, which generally is with a third layer atom, either the Pt atom under the dimer row or the Ge atom in the trough. This removal causes a lowering of the dimer structure into the surface consequently causing a lowering of the electronic structure and hence dimming the dimer image in the pseudo-STM pictures even further. The change in the z -position of the dimer atoms is not the only geometrical effect caused by this removal. The dimers also bend toward one another over the location of the removed Ge atom. Consequently the two dimer images in the pseudo-STM picture merge into one single heart-shaped feature, of which the orientation depends on the bias, as can be seen in Figure 11.

3. Missing dimers or hidden dimers?

In the previous two paragraphs it was shown that the introduction of Pt in the second or third layer causes significant changes in the electronic structure of the surface. The difference in height/brightness of the dimer images in the pseudo-STM pictures depends largely on the simulated bias. Combining the information from the visual STM-image with the height differences, at different biases (both positive and negative), of the maxima should make it possible to clearly distinguish the different ge-

ometries containing Pt in the second and third layer in experiment.

For a Pt atom in the second layer at the down location, the maxima calculated for dimers on top of the Pt atom and dimers without Pt nearby, are roughly the same (less than 0.1 Å). Here the image at positive bias would give the telltale signature with the dimmed oval structure over a pair of down Ge dimer atoms, which is ~ 0.45 Å lower at +0.70 V and ~ 0.3 Å lower than the maxima at +1.50 V bias.

For second layer Pt atoms at the up location there is the merging of two dimer images into one single rectangular feature, which at low negative bias will shift one full dimer position with regard to the positive bias position. Furthermore, at increasing positive bias the maximum will seem to move to one side of the dimer row. At negative bias, the maximum of the structure will be ~ 0.25 Å lower than that of a normal Ge dimer, with this height difference becoming larger at smaller bias. At positive bias on the other hand the maximum will be about 0.3 Å higher than of a normal Ge dimer.

Pt in the third layer also modifies the electronic structure in a recognizable way. Pt under the dimer row lowers the peaks of the above dimer row by 0.5 to 0.7 Å at negative bias, while a Pt atom in the trough modifies the Ge dimer, with its up Ge atom nearby, by lowering the maxima of these dimers only ~ 0.25 Å. For the latter, these dimers are also slightly more asymmetric than the normal ones and at small positive bias the dimer image is still one feature while for a normal dimer the image splits up into two separate atom images. This splitting still occurs for the modified dimer but at a larger positive bias. At positive bias the modified dimers are highest for both Pt positions. For low positive biases they are ~ 0.25 Å higher, than the normal dimers, while for large positive bias this difference shrinks to only ~ 0.1 Å. Removal of the Ge atoms, which were pushed to the top layer, changes the electronic structure dramatically from the normal Ge dimer image. In each case two dimer images are merged into one single large heart-shaped feature which is about 0.6 to 0.7 Å lower than the maxima of the normal dimers at negative bias, and about 0.8 Å lower at small positive bias. At large positive bias this difference reduces to ~ 0.25 Å at which point the maximum of the structure is located at one side of the dimer row, giving the feature a somewhat butterfly-like appearance.

Combinations as seen in Figure 11 give similar results. For example, the height difference of the dimer images, for Pt in the third layer at positions a and c in the filled-state image is ~ 0.8 Å and in the empty-state image this is ~ 0.2 Å. When the k_1 Ge atom is removed, the filled-state image now gives a height difference of ~ 1.0 Å while the empty-state image shows one of ~ 0.6 Å. For both filled- and empty- state images the normal dimers are highest.

Although we used a very simple model to calculate the pseudo-STM pictures, the values obtained suggest that some of these geometries could cause experimentally observed features in the α -terrace, such as indented dimers

or two dimer vacancies.

Indented dimers are a structure two dimers long and based on the above results we conclude that this feature is caused by a Pt atom in a second layer up position or a third layer trough position. Two dimer vacancies on the other hand might not be actual missing dimers but merely due to the charge transfer from Ge-Ge dimers to a Pt atom in a third layer row position underneath. At this moment the above remains uncertain. A high resolution STM study over varying bias of these defects however, should make a conclusive statement on this subject possible.

IV. CONCLUSIONS

In this paper, we studied the possible geometries containing 0.25 and 0.5 ML of Pt substituted in the top layer of a Ge(001) reconstructed surface. Zero temperature *ab initio* calculations showed that the formation of Pt-Ge dimer rows are the most favorable reconstructions. They also showed the spontaneous formation of anti-phase buckling in most geometries due to the introduction of Pt. Comparison of calculated STM images with experimental observations was necessary to show the β -terrace has a β_{6u} -geometry, which has some similarities with the Ge(001)-c(4×2)-reconstruction. A thorough description the β_{6u} -geometry is given and it is shown that the Pt-Ge dimers are tilted in anti-phase with the Ge-Ge dimers causing, together with the asymmetry of the dimers, a *twisting*, a *bending* and a *shift*

of the original tetrahedral structure of the second and third layer Ge atoms. Additionally, we studied geometries containing Pt atoms substituted in the second and third layer and showed the most stable configuration to be one with Pt atoms located under the Ge dimer row. It was also shown that Pt atoms in this position push a second layer Ge atom to the surface and that the removal of this atom doesn't increase the formation energy but instead decreases it. In all these 'other' geometries, with exception of those where Ge atoms were removed, the presence of Pt atoms both modifies and dims the Ge dimers on top for negative bias and brightens them for positive bias. The height differences found indicate that these other geometries could be responsible for experimentally observed indented dimers and two dimer vacancies. Also, the calculated STM images of these other geometries show clearly that they can not be responsible for the β -terrace, though some are energetically more stable, indicating that the β_{6u} -geometry might be a local minimum.

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 - ²² Geometries containing pure Pt and pure Ge dimers were not considered based on our results for the β -geometries.
 - ²³ Or any of the possible equivalent geometries.
 - ²⁴ An alternative way of calculating the formation energy (which gives exactly the same results) is by calculating the surface formation energy E_{sb} of the β -surface using

the expression,

$$E_{sb} = E_T[\beta_x] - N_{Pt}E_{Pt} - N_{Ge}E_{Ge},$$

where $E_T[\beta_x]$ is the total energy of the β_x -surface, N_X the number of atoms of type X in the slab with E_X the corresponding bulk energy per atom. Substraction of the formation energy caused by the Ge-Ge dimers gives:

$$E_{sb2} = E_{sb} - N_{Ge-dimers}E_{s\ Ge-dimer},$$

with $N_{Ge-dimers}$ the number of Ge-Ge dimers in the β -surface and $E_{s\ Ge-dimer}$ the formation energy of a Ge dimer in the $b(2 \times 1)$ surface reconstruction. The energy E_{sb2} can then be considered the contribution by the Pt-Ge dimers to E_{sb} . After subtraction of the formation energy $E_{s\ Ge-dimer}$ from the calculated energy contribution per Pt-Ge dimer, E_{sb2} , the formation energy per Pt-Ge dimer as given in eq. 1 is obtained. In this derivation the physical meaning of the formation energy is the energy gained/needed when a Ge-Ge dimer is transformed into a Pt containing dimer. This is true under the assumption that there is no contribution to the surface energy due to dimer-dimer interactions or if all changes herein are attributed to the Pt containing dimers and they are assumed to be equal in a single geometry.

- ²⁵ The germanium samples on which the Pt is deposited need to be annealed at a temperature of $> 1000\text{K}$ ($\approx 86\text{meV}$) to make the β -terras (and nanowires) appear.
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- ³⁰ The zero, or nearly zero, band gap for germanium is a known failure of LDA. Although a band gap can be opened using for example the GW method, it is not necessary for the qualitative comparison we are making here. Neither does it have any influence on the metalicity of the β_{6u} structure.
- ³¹ Figure 2 in Gay *et al* gives a diagrammatic representation of a $\text{Ge}(2 \times 2)$ reconstruction.
- ³² Using the notation of Gay *et al.* the β_{6u} -surface could be written as $\text{Ge/PtGe}(\text{up})$.
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- ³⁴ This is understandable since the Pt-Ge bond is energetically favorable over a Pt-Pt or a Ge-Ge bond.